

Chemical Vapour Deposition Synthesis of Novel Nanostructured Materials

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DECLARATION

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APPENDIX: PUBLICATIONS ARISING FROM THIS THESIS

Part of the work presented in this thesis has been published to refereed journals. The following is lists of publications that have arisen as a result of work presented in this thesis.

- (1) **A. Supangat**, G. Bryant, W. J Belcher and P. C. Dastoor, “Synthesis of Indium Oxide Nanowires Encapsulated in Amorphous Carbon Nanostructures on Indium Tin Oxide Substrate”, *Materials Research Innovations*.
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- (2) **A. Supangat**, X. Zhou, W. J. Belcher and P. C. Dastoor, “Chemical vapour deposition of poly(p-phenylenevinylene) nanofilms for use in organic photovoltaics”, *Materials Research Innovations*, Vol 15, 2011. pp. 18-20
- (3) **A. Supangat**, G. Bryant, W. J. Belcher and P. C. Dastoor, “Templated Growth of Poly (p-phenylenevinylene) Nanostructures by Chemical Vapour Deposition”, *Materials Research Innovations*.
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LIST OF FIGURES

Figure 1-1: Current performance and price of different PV module technologies [23] ...	5
Figure 1-2: The graph of current-voltage curve with the illustration of FF, I_{sc} and V_{oc} ...	9
Figure 1-3: Thermal Chemical Vapor Deposition System [44]	11
Figure 1-4: Formation of Carbon Nanotube [62]	12
Figure 1-5: Diagram of reactor used for CVD of PPV [71]	15
Figure 2-1: Evaporator overview and dimensions	19
Figure 2-2: Fe layer thickness versus evaporation time plot	20
Figure 2-3: Schematic diagram of the Atomate CVD system	21
Figure 2-4: SEM image of alumina porous template	23
Figure 2-5: Schematic diagram of CVD polymerisation	25
Figure 2-6: (a) Photo of Philips XL30 SEM & (b) schematic diagram of SEM	26
Figure 2-7: (a) Photo of JEOL 1200 EXII TEM & (b) schematic diagram of TEM	27
Figure 2-8: Schematic of 4-point probe configuration [94]	28
Figure 2-9: Schematic of four-point probe setup for thin rectangular slice sample [94]	28
Figure 2-10: An optimal geometry of the ground state and excited state	32
Figure 2-11: Current density versus voltage characteristics ($J-V$) of an ideal solar cell [39]	35
Figure 3-1: (a) Influence of oxygen gas flow rate [108] and (b) annealing treatment [109]	37
Figure 3-2: Conductivity of ITO substrates at different annealing temperatures	41
Figure 3-3: AFM images of ITO annealed at different temperatures of	44
Figure 3-4: Plot of different surface roughness under different annealing temperatures	45
Figure 3-5: SEM image of ITO annealed at 700°C with the appearance of wrinkles and spikes	46
Figure 3-6: X-ray diffraction pattern of ITO substrate after annealing at (a) 700°C, (b) 600°C,	47

Figure 3-7: Graph of FWHM versus conductivity of (211), (222), (400), (440) & (622) planes.....	47
Figure 3-8: Peak intensity of (222) and (400) versus annealing temperature	48
Figure 3-9: Grain size of crystallites for (400) and (222) planes versus annealing temperature.....	49
Figure 3-10: UV-vis absorption spectra of ITO annealed at different temperature	51
Figure 3-11: EDS spectra of ITO substrate before (a) and after annealing at (b) 100°C, (c) 200°C, (d) 300°C, (e) 400°C, (f) 450°C, (g) 500°C, (h) 600°C & (i) 700°C.....	53
Figure 3-12: EDS spectra of indium peaks of ITO annealed at different temperature ...	53
Figure 3-13: Relative concentration (%) of indium and tin in the bulk composition	54
Figure 3-14: XPS spectra of ITO annealed at different temperatures: (a) wide scan & ..	56
Figure 3-15: Atomic relative concentration (%) of indium and tin at the surface	57
Figure 3-16: Ratio of In:O and Sn:O under different annealed temperatures.....	57
Figure 3-17: XPS spectra in the O1s region of ITO substrate before (a) and after annealing at	59
Figure 3-18: Atomic relative concentration (%) of O 1s chemical state versus	60
Figure 3-19: Atomic relative concentration of indium at the surface and in the bulk under different annealed temperature.....	61
Figure 4-1: SEM images of (a) carbon nanostructures grown on glass and ITO under similar growth conditions (b) carbon nanostructures grown on ITO & (c) cross sectional view of carbon nanostructures grown on ITO [8].....	66
Figure 4-2: TEM images of carbon nanostructures grown on ITO of (a) lower magnification &	66
Figure 4-3: SEM image of carbon nanocoils grown at 700°C [140].....	67
Figure 4-4: Schematic diagram of tin nanowire growth by the VLS mechanism [22] ...	68
Figure 4-5: Schematic depiction of silicon nanowire growth by the SLS mechanism [141].....	69
Figure 4-6: TEM image of tin nanowires encapsulated in amorphous carbon nanotube [22].....	70
Figure 4-7: EDX spectroscopic mapping image of indium (red) at the.....	71

Figure 4-8: SEM image (taken at 20000x magnification) of ITO (a) before and after (b) 10 min,	74
Figure 4-9: Schematic illustration of the observed ITO film fragmentation at different hydrogen reduction times	74
Figure 4-10: XPS spectra of ITO (a) before reduction and under the hydrogen reduction at 450°C of (b) 10 min, (c) 30 min and (d) 60 min	74
Figure 4-11: SEM image (taken at 20000x magnification) of 5 nm Fe (a) before and after (b) 10 min & (c) 60 min of hydrogen reduction at 450°C	76
Figure 4-12: Schematic illustration of the proposed Fe/ITO film fragmentation at different hydrogen reduction times	76
Figure 4-13: SEM images (taken at 20000x magnification) of nanostructures grown at 450°C for 10 min under the different system pressures of (a) 100 Torr (b) 200 Torr (c) 300 Torr & (d) 400 Torr	77
Figure 4-14: Illustration of interface layer and nanostructured layer within the carbon nanostructures	77
Figure 4-15: Interface layer thickness at different pressure	78
Figure 4-16: XPS spectrum of C peak at 284.5eV of carbon nanostructures	79
Figure 4-17: SEM images (taken at 20000x magnification) of (a) carbon nanostructures grown at 200 Torr after H ₂ plasma etching at different times of (b) 10 min (c) 30 min (d) 120 min (e) 240 min & (f) 360 min	82
Figure 4-18: Amorphous carbon film thickness at different etching time	85
Figure 4-19: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 400°C of 100 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	86
Figure 4-20: 3D graph distribution of relative atomic concentration of O, C, In and Fe growth at 400°C and 100 Torr of different growth time	87
Figure 4-21: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 400°C of 200 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	89
Figure 4-22: 3D graph distribution of relative atomic concentration of O, C, In and Fe growth at 400°C and 200 Torr of different growth time	91

Figure 4-23: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 400°C of 300 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	92
Figure 4-24: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 400°C of 400 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	94
Figure 4-25: 3D graph distribution of relative atomic concentration of O, C, In and Fe growth at 400°C and 400 Torr of different growth time.....	94
Figure 4-26: FESEM images of (a) cross-section & (b) top-view of nanostructures grown at 450°C of 100 Torr for 1 min	95
Figure 4-27: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 450°C of 100 Torr for 5 min (a-c) and 10 min (d-f).....	96
Figure 4-28: Graph distribution of relative atomic concentration of O, C, In and Fe growth at 450°C and 100 Torr of different growth time.....	96
Figure 4-29: High resolution TEM images of carbon nanostructures grown at 450°C ..	97
Figure 4-30: TEM image showing the (a) lattice image of carbon nanostructure & Fast Fourier transform of the image (inset) and (b) plot profile of lattice image	98
Figure 4-31: Schematic illustration of the MWCNT nucleation and growth processes	100
Figure 4-32: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 450°C of 200 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	102
Figure 4-33: High resolution TEM image of carbon nanostructure grown at 450°C ...	103
Figure 4-34: High resolution TEM image of particle encapsulated.....	104
Figure 4-35: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 450°C of 300 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	105
Figure 4-36: 3D graph distribution of relative atomic concentration of O, C, In and Fe growth at 450°C and 300 Torr of different growth time.....	106
Figure 4-37: High resolution TEM images (a & b) and the corresponding fast Fourier transform (c).....	107
Figure 4-38: XPS spectrum of carbon nanostructure grown at 450°C of 300 Torr for 10 min	108

Figure 4-39: FESEM images (cross-section and top view) and EDX data (line scan) .	110
Figure 4-40: (a) A high resolution TEM image of carbon nanostructure grown at 450°C of 400 Torr for 10 min (inset: SEM image). (b) An image magnified from the yellow box in (a). (c) An image magnified from the yellow box in (b) and its fast Fourier transform image (inset)	111
Figure 4-41: (a) SEM image (b-d) TEM images of indium oxide nanostructure encapsulated by carbon layer grown at 400 Torr and (e) Selected area diffraction pattern of image in (d).....	113
Figure 4-42: XPS spectrum of indium oxide nanostructure encapsulated by carbon layer	114
Figure 4-43: XPS spectrum of ITO substrate.....	114
Figure 4-44: Schematic illustration of the proposed growth mechanism of indium oxide nanostructures encapsulated by carbon layer at 400 Torr	117
Figure 4-45: Raman spectra of carbon nanostructures obtained at 450°C	119
Figure 4-46: Raman spectrum of indium oxide nanostructures	120
Figure 4-47: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 500°C of 100 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	122
Figure 4-48: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 500°C of 200 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	123
Figure 4-49: FESEM images of (a) cross-section & (b) top-view of nanostructures grown at 500°C of 300 Torr for 1 min	124
Figure 4-50: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 500°C of 300 Torr for 5 min (a-c) and 10 min (d-f).....	124
Figure 4-51: FESEM images (cross-section and top view) and EDX data (line scan) of nanostructures grown at 500°C of 400 Torr for 1 min (a-c), 5 min (d-f) and 10 min (g-i)	126
Figure 5-1: Images of thin polymeric films on silicon trenches deposited by (a) spin coating a polymer solution and (b) CVD[59]	131
Figure 5-2: SEM images of poly(3,4-ethylenedioxythiophene) coated poly(acrylonitrile) fiber mats prepared by (a) spin casting and (b) CVD[180].....	131

Figure 5-3: Preparation scheme of 1,9-dichloro [2,2] paracyclophane [72]	133
Figure 5-4: Preparation of PPV via the vapor deposition polymerisation of 1,9-dichloro [2,2] paracyclophane [72]	134
Figure 5-5: Absorbance of PPV precursor (solid line) and PPV(dashed line), and photoluminescence of PPV (dotted line) [71].....	135
Figure 5-6: IR spectra (transmittance vs wavenumber) of (a) precursor and (b) PPV [72]	136
Figure 5-7: Absorption spectra of the unirradiated and the irradiated PPV films [100]	138
Figure 5-8: Photodegradation mechanism of PPV in air [100].....	139
Figure 5-9: Absorption and photoluminescence spectra of oligomers with a) 1, b) 2, c) 3, d) 4,	139
Figure 5-10: PPV precursor synthesis via CVD polymerisation	140
Figure 5-11: PPV synthesis via thermal de-hydrohalogenation.....	141
Figure 5-12: Calibrated deposition zone positions	142
Figure 5-13: UV-Vis absorption spectra of pristine quartz and PPV precursor	143
Figure 5-14: UV-Vis absorption spectra of PPV precursor located at spots 1 to 7	143
Figure 5-15: Time versus surface temperature of spot 1 and 2 at 700°C pyrolysis temperature.....	145
Figure 5-16: Time versus surface temperature of spot 3 to 7 at 700°C pyrolysis temperature.....	145
Figure 5-17: Fourier Transform IR spectrum of chlorine PPV precursor.....	146
Figure 5-18: Fourier Transform IR spectrum of bromine PPV precursor	147
Figure 5-19: UV-Vis absorption spectra of chlorine precursor and PPV	150
Figure 5-20: Fourier Transform IR spectra of chlorine precursor and PPV	151
Figure 5-21: Photoluminescence spectrum of chlorinated PPV (excitation at 350 nm)	151
Figure 5-22: PL spectrum of PPV with six uninterrupted phenylenevinylene units [102]	152

Figure 5-23: Chemical structure of PPV containing six phenylenevinylene units	153
Figure 5-24: UV-Vis absorption spectra of bromine precursor and PPV	154
Figure 5-25: Fourier Transform IR spectra of bromine precursor and PPV	154
Figure 5-26: UV-Vis absorption spectra of chlorinated PPV and brominated PPV	157
Figure 5-27: Fourier Transform IR spectra of chlorinated PPV and brominated PPV	157
Figure 5-28: UV-Vis spectra of PPV converted at different time.....	158
Figure 5-29: Fourier Transform IR spectra of chlorine precursor and 2 hours heated to PPV	160
Figure 5-30: UV-Vis absorption spectrum of a quartz substrate	162
Figure 5-31: UV-Vis absorption spectra of Cl-PPV after being exposed to air for up to 6 months	163
Figure 5-32: UV-Vis absorption spectra of Br-PPV after being exposed to air for up to 6 months	164
Figure 5-33: The current voltage characteristics of an ITO/PPV/PCBM/Al in the dark and under illumination of AM-1.5	166
Figure 5-34: The current voltage characteristics of an ITO/PPV/C ₆₀ /Al in the dark and under illumination of AM-1.5	166
Figure 5-35: The current voltage characteristics of (a) ITO/PEDOT/PPV/PCBM/LiFAl and (b) ITO/PEDOT/PPV/C ₆₀ /LiFAl in the dark and under illumination of AM-1.5 ..	167
Figure 5-36: The current voltage characteristics of (a) ITO/PEDOT/PPV/PCBM/CaAl and (b) ITO/PEDOT/PPV/C ₆₀ /CaAl in the dark and under illumination of AM-1.5....	169
Figure 5-37: External Quantum Efficiency (EQE) spectrum of PPV/C ₆₀	169
Figure 5-38: The efficiencies of cells produced by different device architectures	170
Figure 6-1: SEM images of PPV (a) nanotubes prepared in alumina filter membrane & (b) nanorods prepared in polycarbonate filter membrane [70]	172
Figure 6-2: SEM images of PTV nanotubes prepared by alumina filter membrane [11]	173
Figure 6-3: Schematic diagram of template positioned at (a) horizontal (0°) (b) 30° (c) 45° (d) 60° & (e) vertical (90°) respect to the planar surface	174

Figure 6-4: Photoluminescence spectra (excitation at 350 nm) of PPV deposited on alumina template of different angles.....	176
Figure 6-5: Photoluminescence intensity ratio of peak 1 to peak 2 of different deposition angles.....	176
Figure 6-6: SEM image of PPV deposited on horizontal alumina template of (a) lower magnification & (b) higher magnification	178
Figure 6-7: SEM image (Top view) of PPV deposited on alumina porous template taken from the bottom surface	178
Figure 6-8: Cross-section SEM image of PPV deposited on horizontal alumina template	179
Figure 6-9: Photoluminescence spectra (excitation at 350 nm) of PPV thin film deposited on quartz and PPV nanostructure deposited on alumina template at 0°	180
Figure 6-10(a-d): SEM image of PPV deposited on horizontal alumina template after being isolated from template.....	182
Figure 6-11: Schematic diagram of proposed nanostructure of fibrous-like PPV	182
Figure 6-12: SEM image of PPV deposited at 30° of alumina template angle of (a) lower magnification & (b) higher magnification	183
Figure 6-13: Cross-section SEM image of PPV deposited at 30° of alumina template angle	183
Figure 6-14: SEM image of PPV (a-c) deposited at 30° of alumina template angle after being isolated from template.....	184
Figure 6-15: Schematic illustration of the proposed formation of PPV nanotubes synthesis at deposition template angle of 30°Angle at 45°	185
Figure 6-16: SEM image of PPV deposited at 45° of alumina template angle of (a) lower magnification & (b) higher magnification	185
Figure 6-17: Cross-section SEM image of PPV deposited at 45° of alumina template angle	185
Figure 6-18: Photoluminescence spectra (excitation at 350nm) of PPV thin film deposited on quartz and PPV deposited on alumina template at 45°	186
Figure 6-19: SEM image of PPV (a-c) deposited at 45° of alumina template angle after being isolated from template.....	187

Figure 6-20: SEM image of PPV deposited at 60° of alumina template angle of (a) lower magnification & (b) higher magnification	188
Figure 6-21: Cross-section SEM image of PPV deposited at 60° of alumina template angle	188
Figure 6-22: SEM image of PPV (a-c) deposited at 60° of alumina template angle after being isolated from template	189
Figure 6-23: Photoluminescence spectra (excitation at 350 nm) of PPV thin film deposited on quartz and PPV deposited on alumina template at 60°	189
Figure 6-24: SEM image of PPV deposited on vertical alumina	191
Figure 6-25: Cross-section SEM images of PPV deposited on vertical alumina template	191
Figure 6-26: SEM image of PPV (a-d) deposited at 90° of alumina template angle after being isolated from template	193
Figure 6-27: Schematic illustration of the proposed formation of PPV nanotubes synthesis at deposition template angle of 90°	193
Figure 6-28: Photoluminescence spectra (excitation at 350 nm) of PPV thin film deposited on quartz and PPV deposited at different alumina template angles	194

LIST OF TABLES

Table 2-1: Recipe used in synthesizing the carbon nanostructures.....	22
Table 3-1: Description on the terminology of surface roughness	45
Table 5-1: Peaks and corresponding assignments of bromine PPV precursor in infrared	148

Table of Contents

1	INTRODUCTION AND MOTIVATION.....	1
1.1	CHALLENGES AND ISSUES.....	1
1.2	RESEARCH OBJECTIVES.....	2
1.3	ORGANISATION OF THESIS	3
1.4	PHOTOVOLTAIC TECHNOLOGY	4
1.5	ORGANIC PHOTOVOLTAICS (OPVs)	5
1.6	THE IMPORTANCE OF NANOSTRUCTURE IN OPVs	9
1.7	CARBON NANOTUBES (CNTs).....	12
1.7.1	Fabrication Methods and Mechanisms	12
1.7.2	Use in OPVs.....	13
1.8	POLYMER NANOSTRUCTURES.....	14
1.8.1	Fabrication.....	14
1.8.2	Use in OPVs.....	16
2	EXPERIMENTAL.....	17
2.1	FABRICATION OF CARBON NANOTUBES	17
2.1.1	Catalyst Layer Deposition.....	17
2.1.2	Thermal Chemical Vapour Deposition	20
2.2	FABRICATION OF POLYMER NANOTUBES.....	22
2.2.1	Alumina Porous Template.....	22
2.2.2	Chemical Vapour Deposition Polymerisation.....	23
2.3	CHARACTERISATION.....	25
2.3.1	Scanning Electron Microscopy	25
2.3.2	Transmission Electron Microscopy	26
2.3.3	Conductivity.....	27
2.3.4	Optical Spectroscopy	30
2.3.5	Photoluminescence Spectroscopy	32
2.3.6	X-ray Photoelectron Spectroscopy.....	33
2.4	OPV DEVICE FABRICATION	33
2.5	OPV DEVICE CHARACTERISATION	34
3	EFFECT OF THERMAL TREATMENT ON INDIUM TIN OXIDE SUBSTRATES.....	36

3.1	INTRODUCTION.....	36
3.1.1	Properties of ITO.....	36
3.1.2	Thermal Processing of Organic Electronic Films and Structures	38
3.1.3	Thermal Processing of ITO	39
3.2	EXPERIMENTAL SETUP	40
3.3	RESULTS AND DISCUSSION	41
3.3.1	Conductivity.....	41
3.3.2	Surface Morphology.....	42
3.3.3	Crystallinity.....	46
3.3.4	Optical Properties.....	51
3.3.5	Chemical Composition.....	52
3.3.6	Bulk Measurements.....	52
3.3.7	Surface Measurements	54
3.3.7.1	Combining the Bulk and Surface Compositional Measurements	61
3.4	CONCLUSION	62
4	CHEMICAL VAPOUR DEPOSITION OF CARBON NANOSTRUCTURES ON INDIUM TIN OXIDE	64
4.1	INTRODUCTION.....	64
4.1.1	Overview	64
4.1.2	Carbon nanostructures on ITO.....	65
4.1.3	Semiconducting nanostructures	67
4.2	EXPERIMENTAL SETUP	71
4.3	RESULTS AND DISCUSSION	72
4.3.1	Effect of hydrogen reduction on ITO.....	72
4.3.2	Effect of hydrogen reduction on iron-coated ITO.....	75
4.3.3	The growth of carbon nanostructures.....	76
4.3.4	Characterisation of the interface layer	77
4.3.4.1	Formation of an amorphous carbon layer	77
4.3.4.2	Effect of H ₂ plasma on the interface layer	80
4.3.5	Characterisation of nanostructured layer	85
4.3.5.1	Nanostructure growth at 400°C (100 – 400 Torr).....	85
4.3.5.1.1	Nanostructure growth at 100 Torr	85

4.3.5.1.2	Nanostructure growth at 200 Torr	89
4.3.5.1.3	Nanostructure growth at 300 Torr	91
4.3.5.1.4	Nanostructure growth at 400 Torr	93
4.3.5.2	Nanostructure growth at 450°C (100 – 400 Torr).....	95
4.3.5.2.1	Nanostructure growth at 100 Torr	95
4.3.5.2.2	Nanostructure growth at 200 Torr	101
4.3.5.2.3	Nanostructure growth at 300 Torr	104
4.3.5.2.4	Nanostructure growth at 400 Torr	109
4.3.5.3	Raman spectra at 450°C.....	118
4.3.5.4	Nanostructure growth at 500°C (100 – 400 Torr)	121
4.3.5.4.1	Nanostructure growth at 100 Torr	121
4.3.5.4.2	Nanostructure growth at 200 Torr	122
4.3.5.4.3	Nanostructure growth at 300 Torr	124
4.3.5.4.4	Nanostructure growth at 400 Torr	125
4.3.5.5	Effect of pressure on nanostructure growth.....	126
4.4	CONCLUSIONS	129
5	CHEMICAL VAPOUR DEPOSITION OF PPV AND PPV OPV.....	130
5.1	INTRODUCTION.....	130
5.1.1	Motivation for Polymer Synthesis by CVD.....	130
5.1.2	CVD Approaches to PPV Thin Film Formation.....	132
5.1.3	OPV Devices Made from PPV Films.....	136
5.1.4	Degradation of PPV films	137
5.2	EXPERIMENTAL SETUP	140
5.3	RESULTS AND DISCUSSION	142
5.3.1	PPV Precursor Absorbance.....	142
5.3.2	PPV Absorbance	149
5.3.3	Influence of Monomer Selection on Optical Properties.....	155
5.3.4	PPV Absorbance with Thermal Conversion Time.....	158
5.3.5	Degradation of Processed PPV Film.....	162
5.3.6	Integration of CVD PPV into OPV devices.....	165
5.4	CONCLUSIONS	171

6	CHEMICAL VAPOUR DEPOSITION OF THE PPV NANOSTRUCTURES	172
6.1	INTRODUCTION.....	172
6.2	EXPERIMENTAL DETAILS.....	174
6.3	RESULTS AND DISCUSSION	175
6.3.1	Photoluminescence.....	175
6.3.2	Surface morphology of PPV as a function of deposition angle	177
6.3.2.1	Horizontal (0°).....	177
6.3.2.2	Angle at 30°	182
6.3.2.3	Angle of 45°	185
6.3.2.4	Angle at 60°	187
6.3.2.5	Vertical angle (90°).....	189
6.3.3	Effect of nanostructures on optical emission	194
6.4	CONCLUSIONS	196
7	SUMMARY AND FURTHER WORK.....	197
7.1	SUMMARY	197
7.2	FURTHER WORK.....	199

ABSTRACT

The growth of carbon and poly-*p*-phenylene vinylene (PPV) nanostructures via chemical vapour deposition (CVD) has been studied. Working temperatures of 400, 450 and 500°C and 270°C have been applied for the growth of carbon and PPV, respectively. In this work, indium tin oxide (ITO) modified by the CVD growth of carbon nanostructures has been used as an electrode in the fabrication of organic photovoltaic (OPV) devices. Therefore, the effect of thermal treatment on ITO conductivity, physical properties and chemical composition is studied.

The growth of carbon nanostructures on ITO is studied under a variety of CVD conditions, in particular, the effect of varying growth time, temperature and system pressure have been investigated. Pressures between 100 and 400 Torr were used during the growth of the carbon nanostructures. Two layers, comprising a dense amorphous interface layer and the nanostructured layer have been observed at all pressures in this range. However, an abrupt change at the interface and nanostructured layer was seen at 400 Torr. The thickness of the interface layer, which is composed of amorphous carbon, is directly proportional to the system pressure. H₂ plasma treatment has been applied to reduce the amorphous carbon layer thickness. Multiwalled carbon nanotubes (MWCNTs) have been successfully synthesised at pressures between 100 and 300 Torr. The diffusion of indium from the substrate into the nanostructured layer is observed to occur at 450°C and 400 Torr which initiates the growth of indium oxide nanowires encapsulated by a carbon layer.

Presented here for the first time is an OPV whose active layer has been fabricated via the CVD technique. A PPV nanofilm is synthesised by CVD onto ITO without the use of solvent or solution. Two different monomers, α,α' -dichloro-*p*-xylene and α,α' -dibromo-*p*-xylene, are used and the properties of the chloro-derived PPV and bromo-derived PPV is compared for the future fabrication. The chloro-derived PPV has an advantage over bromo-derived PPV in terms of the energy band gap and conjugation length. As a consequence, an OPV is wholly fabricated by the starting monomer of α,α' -dichloro-*p*-xylene.

To realise PPV nanostructures that could potentially be integrated into OPV devices, CVD based polymerisation of PPV in a porous alumina template has been investigated.

Five different angles of the template with respect to the gas flow were tested. A series of interesting PPV nanostructures such as fibre-like and nanotubes have been effectively synthesised via this method.